

PS2501-1, -4, PS2501L-1, -4

HIGH ISOLATION VOLTAGE SINGLE TRANSISTOR TYPE

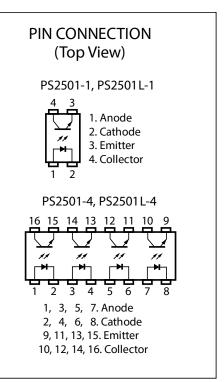
DESCRIPTION

The PS2501-1, -4 and PS2501L-1, -4 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor.

The PS2501-1, -4 are in a plastic DIP (Dual In-line Package) and the PS2501L-1, -4 are lead bending type (Gull-wing) for surface mount.

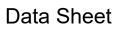
FEATURES

- High isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (V_{CEO} = 80 V)
- High-speed switching ($t_r = 3 \mu s$ TYP., $t_f = 5 \mu s$ TYP.)
- Ordering number of taping product: PS2501L-1-F3 : 2 000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL1577, Double protection



APPLICATIONS

- Power supply
- Telephone/FAX.
- FA/OA equipment
- Programmable logic controller



R08DS0202EJ0100

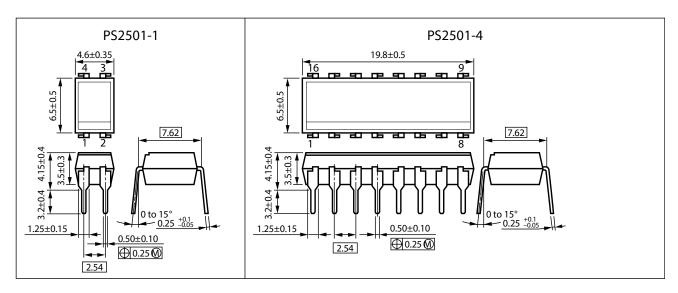
Rev.1.00

Dec 25, 2020

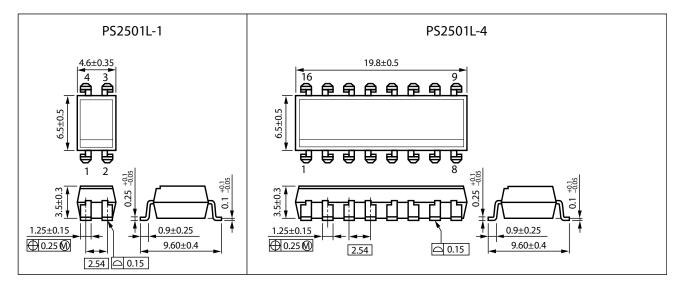


PACKAGE DIMENSIONS (UNIT: mm)

DIP Type



Lead Bending Type For Surface Mount



Weight (4-pin DIP) : 0.26 g (typ.)

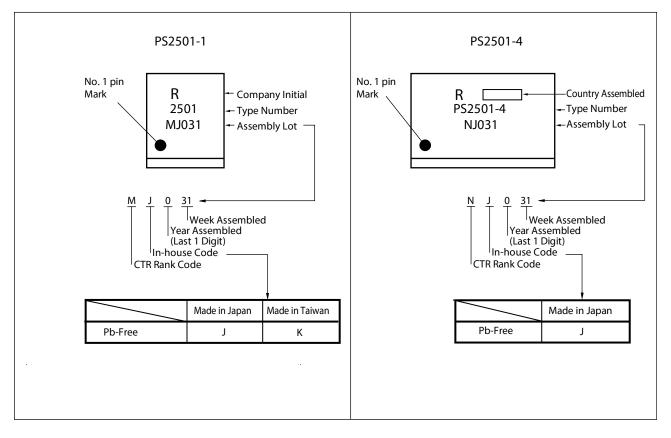
Weight (16-pin DIP) : 1.02 g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (mm)
Air Distance (MIN.)	7
Creepage Distance (MIN.)	7
Isolation Distance (MIN.)	0.3



MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number *1	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number *2
PS2501-1	PS2501-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2501-1
PS2501L-1	PS2501L-1-A			(UL approved)	PS2501L-1
PS2501L-1-F3	PS2501L-1-F3-A		Embossed Tape 2 000 pcs/reel		PS2501L-1
PS2501-4	PS2501-4-A		Magazine case 20 pcs		PS2501-4
PS2501L-4	PS2501L-4-A				PS2501L-4

Notes: *1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank : PS2501-1-A/L

Notes: *2. For the application of the Safety Standard, following part number should be used.



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter			Ratings		
		Symbol	PS2501-1, PS2501L-1	PS2501-4, PS2501L-4	Unit
Diode	Reverse Voltage	V _R	6 V		V
	Forward Current (DC)	IF	80		mA/ch
	Power Dissipation Derating	⊿P₀/°C	1.5	1.2	mW/°C
	Power Dissipation	PD	150	120	mW/ch
	Peak Forward Current *1	I _{FP}	1		A/ch
Transistor	Collector to Emitter Voltage	VCEO	80		V
	Emitter to Collector Voltage	VECO		7	V
	Collector Current	lc	50		mA/ch
	Power Dissipation Derating	⊿Pc/°C	1.5	1.2	mW/°C
	Power Dissipation	Pc	150	120	mW/ch
Isolation Voltage *2		BV	5 000		Vr.m.s.
Operating Ambient Temperature		T _A	–55 to +100		°C
Storage Temperature		T _{stg}	-55 to +150		°C

Note: *1. PW = 100 μ s, Duty Cycle = 1 %

*2. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output. Pins 1-2 shorted together, 3-4 shorted together.

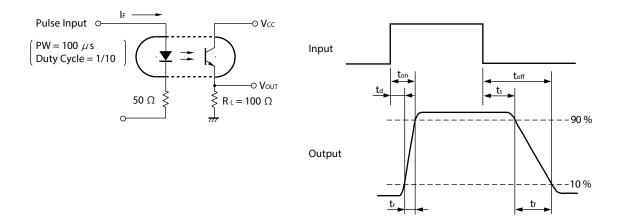


ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.17	1.4	V
	Reverse Current	lr	V _R = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		50		pF
Transistor	Collector to Emitter Dark Current	Iceo	Vce = 80 V, IF = 0 mA			100	nA
Coupled	Current Transfer Ratio (Ic/IF) *1	CTR	IF = 5 mA, Vce = 5 V	80	300	600	%
	Collector Saturation Voltage	VCE (sat)	IF = 10 mA, Ic = 2 mA			0.3	V
	Isolation Resistance	RI-0	VI-0 = 1.0 kVDC	10 ¹¹			Ω
	Isolation Capacitance	Сі-о	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time ^{*2}	tr	Vcc = 10 V, Ic = 2 mA, RL = 100 Ω		3		μs
	Fall Time ^{*2}	tr			5		

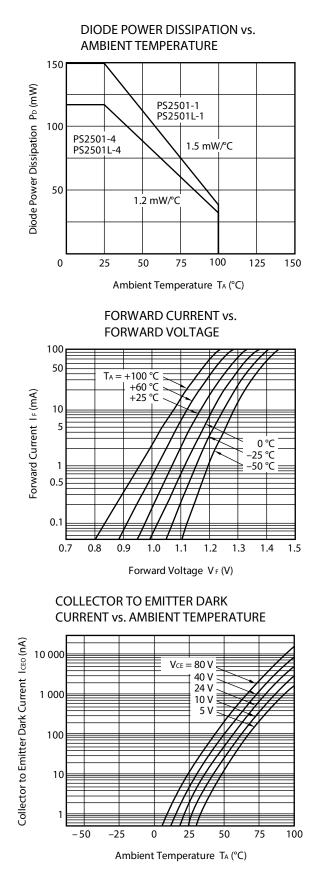
Note : *1. CTR rank (* : only PS2501-1, PS2501L-1)

*2. Test Circuit for Switching Time

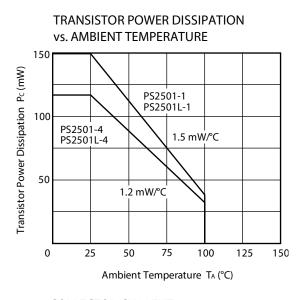




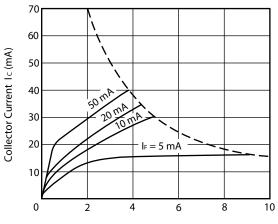
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)





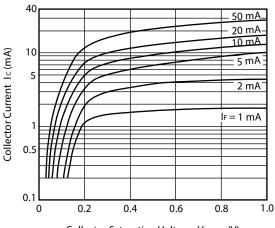


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



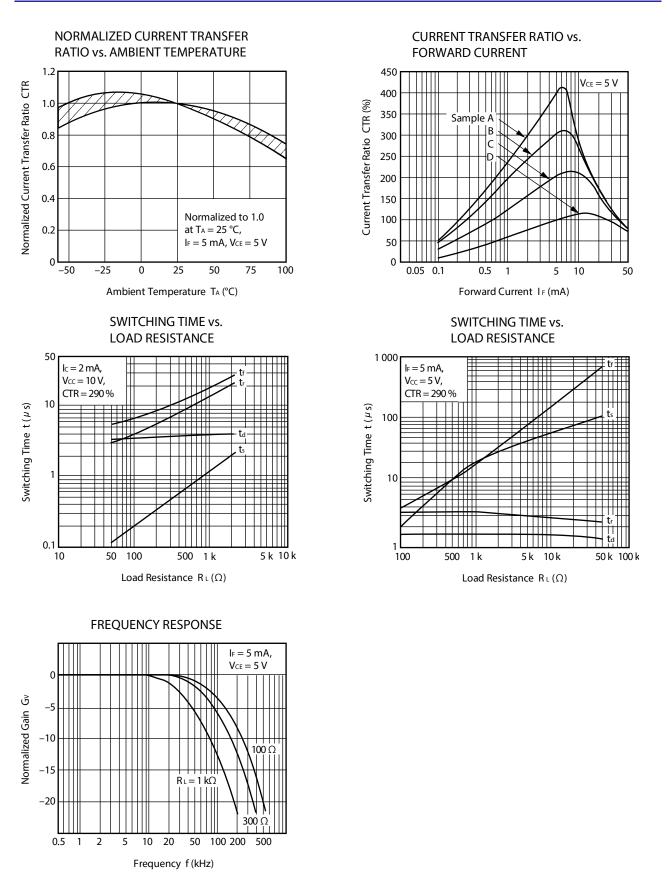
Collector to Emitter Voltage VCE (V)

COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



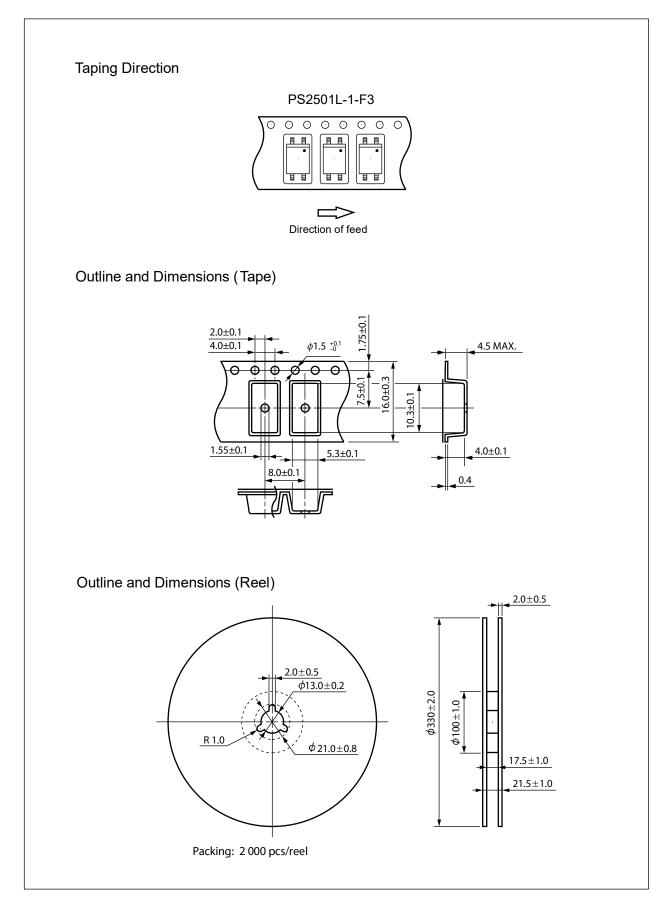
Collector Saturation Voltage VCE (sat) (V)





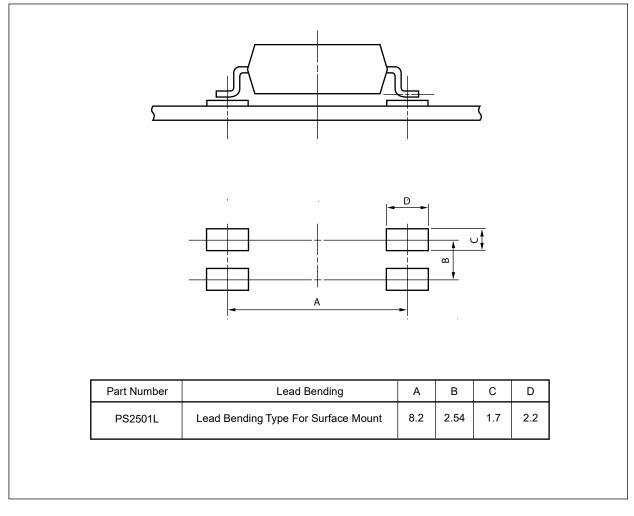
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)





RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

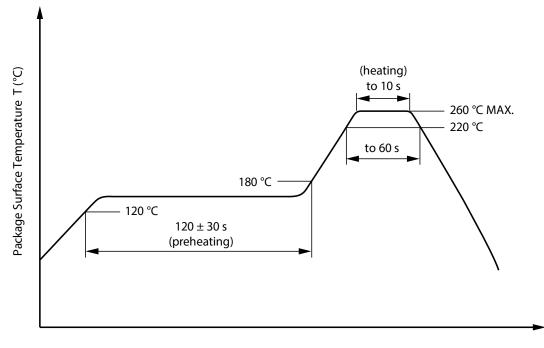


NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature
 - Time of peak reflow temperature
 - Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

260 °C or below (package surface temperature)
10 seconds or less
60 seconds or less
120 ± 30 s
Three
Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120 °C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Time (each pins)

- Peak Temperature (lead part temperature) 350 °C or below
 - 3 seconds or less
- Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100 $^\circ$ C

(4) Cautions

Flux Cleaning

Avoid cleaning with Freen based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.



2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

 Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below $I_F = 1$ mA.

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.
- 3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- 4. Do not use fixing agents or coatings containing halogen-based substances.



Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or i any way allow it to enter the mouth.

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